

Supplementary Information

Molecular Self-Assembly in a Poorly Screened Environment: F₄TCNQ on graphene/BN

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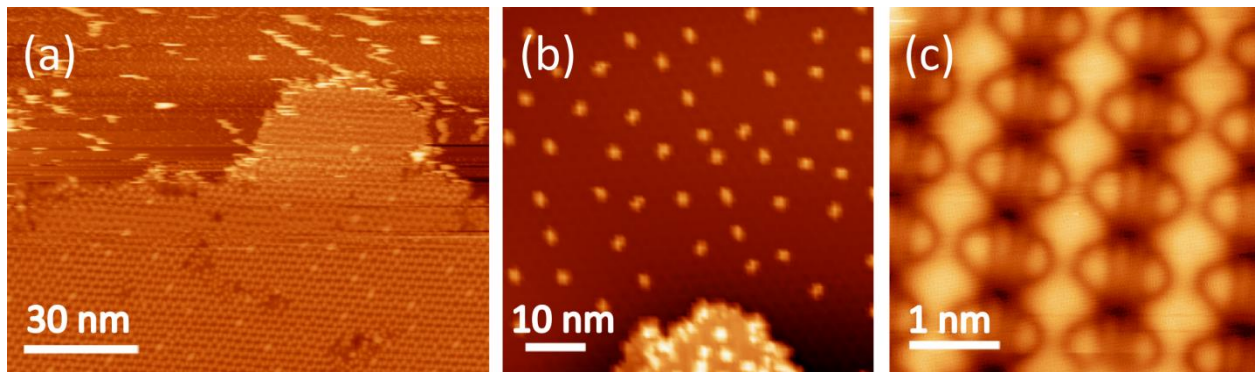


Figure S1: (a) A large scale STM image of F₄TCNQ/graphene/BN at high molecular coverage ($V_s = 2$ V, $I_t = 10$ pA, $T = 4.5$ K), (b) Single F₄TCNQ molecules coexisting with a molecular island on graphene/BN ($V_s = 2$ V, $I_t = 5$ pA, $T = 4.5$ K). (c) A zoom-in image of the island in (b) ($V_s = 2$ V, $I_t = 5$ pA, $T = 4.5$ K).